Hybrid mode-lock InGaAsP/InP MQW laser as a multiwavelength source for WDM

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ABSTRACT

A hybrid mode-locked semiconductor laser was demonstrated as a multi-wavelength light source for WDM networks. The laser simultaneously provides over 50 WDM channels spaced at 21.8 GHz (0.17 nm). Channel spacing is temperature independent and is determined by the modulating frequency applied to the absorber section of the laser, thus is very stable. The wavelength of the channels can be slightly tuned by injection current and/or temperature. We demonstrate dropping a WDM channel at a network node by using a Fiber Bragg Grating combined with a fiber coupler.

Key words: Wavelength division multiplexing, mode locked laser, Fiber Bragg Grating

1. INTRODUCTION

Wavelength Division Multiplexing (WDM) is now widely acknowledged as one of the most promising technology to meet the challenge of the ever increasing demand on telecommunication capacity, and is being rapidly deployed. WDM systems utilize the large bandwidth available from an optical fiber very effectively by launching multiple closely spaced optical channels into a single fiber, each modulated at high bit-rate, e.g., 2.5 Gb/s or 10 Gb/s. The use of multiple wavelengths also offers another degree of freedom to overcome the bandwidth limitation placed either by high speed electronics available or by fiber dispersion, as in the case of using a single wavelength source.

One of the key components of a WDM system is a multi-wavelength light source. Wavelength stability, precise control of channel spacing, low crosstalk, and cost effectiveness are some of the important requirements for WDM light sources.

A large number of multi-wavelength sources have been proposed and demonstrated. Some examples are as follows: a set of discrete DFB lasers, each has a desired wavelength, monolithically integrated semiconductor laser array with each element having slightly different wavelength, spectral slicing of devices with a broad optical emission spectrum, for example, light emitting diode, or semiconductor optical amplifier, a multi-frequency laser with a waveguide grating router as an intracavity element to lock all wavelengths at a specifically determined channel spacing, amplification of spontaneous emission from a Fabry-Perot (F-P) laser biased below threshold, super continuum (SC) generation in optical fiber, tunable DFB lasers, and mode-locked semiconductor laser. Among all the WDM sources proposed to date, the mode-locked semiconductor laser has the following unique advantages: Tens to hundreds different wavelengths can be generated simultaneously with equally spaced channels. The channel spacing is basically determined by the laser cavity length. The application of an RF signal to the saturable absorber section of the mode-locked laser makes the channel spacing temperature independent and very stable. Fine tuning of the channel spacing can be accomplished by...
slightly changing the RF modulation frequency from the cavity repetition rate. This kind of WDM source
is well suitable for the network infrastructure where the multi-wavelength source is located at the central	node and different wavelength is individually modulated at each network node\textsuperscript{10}.

2. LASER STRUCTURE, FABRICATION, AND CHARACTERISTICS

In this work, the hybrid mode-locking of a semiconductor laser was demonstrated. The laser was
a monolithic integration of a long gain section and a short saturable absorber. A schematic drawing of
the mode-locked laser is shown in Fig. 1. The active layer consists of four compressively strained
quantum wells, grown by MOCVD. The device uses a buried heterostructure to form reverse biased
junctions as current blocking layers and also to provide lateral optical confinement. The device length is
2010 \textmu m while the absorber section is only \textasciitilde 100 \textmu m. The isolation region between the gain and the
absorber section is approximately 15 \textmu m. Electrical isolation between the two sections is 1.5 k\Omega. No
coatings were applied to the end facets of the laser. The round trip repetition frequency, calculated from
the cavity length is \textasciitilde 21.8 GHz. The laser showed excellent static characteristics. Threshold current of
the laser with unbiased absorber is as low as \textasciitilde 35 mA, despite the very long cavity length. The slope
efficiency is \textasciitilde 0.055 mW/mA. The emission wavelength is \textasciitilde 1550 nm.

In order to make the absorber section suitable for high frequency modulation, the parasitic
capacitance has to be reduced. Two factors contribute to the parasitic capacitance, one is the distributed
capacitance from the reverse biased block junction, the other is the contact bonding pad capacitance
(contact RC).

In our laser, an isolated narrow mesa (\textasciitilde 10 \textmu m in width) was formed by etching a pair of
channels along the active region. This reduced the capacitance caused by the reverse-biased blocking
layers. A thick SiO\textsubscript{2} layer was deposited on the top surface of the device to isolate the contact. An air
bridge contact configuration has been adopted to provide electrical contact to the absorber section\textsuperscript{11}. This further reduced the parasitic capacitance caused by the metal/SiO\textsubscript{2}/semiconductor interface
compared with a continuous contact configuration in which the contact metal continuously covers the
bottom surface of the isolation channel.

The monolithic device was mounted on a custom high frequency mount consisting of a k-
connector and a 50 \textOmega co-planner. This mount allows RF modulation up to 40 GHz. The laser was not
impedance matched to the co-planner. The frequency response of the absorber (see Fig. 2) was measured
using a network analyzer and a high speed photodetector. The gain section was pumped at 130 mA and
the absorber was DC biased at \textasciitilde 0.26 V. A cavity resonance peak occurs at around 21.8 GHz.

3. MODE-LOCKING OF THE LASER

The laser was first passively mode-locked. In this case, the gain and absorber section were DC
biased under the conditions mentioned above. No RF signal was applied to the absorber. The RF
spectrum of the light output was measured with a high speed detector and an electrical spectrum analyzer
(see Fig. 3, solid line). The passive mode-locking resonance occurred at 21.805 GHz while the 3 dB
linewidth of the electrical spectrum was 9 MHz.

In order to stabilize the channel spacing and make it temperature independent, we hybridly mode-
locked the laser by applying an RF signal to the reverse biased absorber. The network analyzer was used
as an RF source and the modulating power was boosted to +17 dBm with an RF amplifier. The RF
spectrum of the hybridly mode-locked laser is shown in Fig. 3 for two different RF modulation frequencies: 21.764 GHz and 21.83 GHz (dash lines). Contrast ratio of peak to background noise for hybrid mode-locking is larger than 20 dB. The linewidth of the RF spectrum was reduced to 400 KHz. A locking range of 66 MHz was observed around the passive mode-locking resonance. Over 50 WDM channels spaced at 21.8 GHz were demonstrated. Hybrid mode-locking of the device was also realized with an RF signal half the frequency of the cavity round trip rate (10.9 GHz). This sub-harmonic mode-locking eased the need for a very high frequency RF source. Under this condition, the laser remained mode-locked at 21.8 GHz without any noticeable change of the RF spectrum and locking range.

4. EXPERIMENT OF DROPPING A WDM CHANNEL

Using a Fiber Bragg Grating, we demonstrated the principle of dropping a WDM channel. The experiment set up is sketched in Fig. 4. The incoming multi-wavelength signal from the mode-locked laser is split at the 85/15 optical coupler. 85% optical power is connected to a commercially available QPS/Bragg Fiber Grating. The WDM channel of interest that needs to be dropped is reflected off the Bragg Grating back into the coupler and is available at the backward 15% output port of the coupler. All the other channels are available at the output of the fiber grating. The complete WDM spectrum (before dropping) can be measured at the forward 15% output port of the coupler.

The center wavelength of the Fiber Bragg Grating is 1539.3 nm, the peak reflectivity is 93%, and the FWHM is 0.21 nm (26.6 GHz). In order to have the wavelength of one of the WDM channels coincide with the center wavelength of the Fiber Bragg Grating, we can fine-tune the whole wavelength continuum of the mode-locked laser by changing either the temperature or the drive current of the gain section. In our case, the laser was temperature stabilized and wavelength was tuned by changing the injection current into the gain section. It was observed when the injection current changed from 100 mA to 160 mA, the spectrum of the mode-locked laser could be tuned over one channel spacing (0.17 nm). Within this range, the laser stayed hybridly mode-locked with a background noise suppression ratio of more than 20 dB.

The optical spectrum of all three outputs of the setup are shown in Fig. 5. The spectrum of the dropped channel and the change of the WDM signal spectrum after one channel was dropped can be seen clearly.

5. SUMMARY

We demonstrate the use of an air-bridge type hybridly mode-locked laser as a WDM source. Channel spacing is temperature independent and change of injection current provides fast and accurate wavelength tuning. Sub-harmonic mode-locking has also been accomplished. A method of dropping a channel using a Fiber Bragg Grating and fiber coupler has been demonstrated.

6. REFERENCES


Figure Captions

Fig. 1  Schematic view of the mode-locked laser showing gain and absorption section, isolated mesa and air-bridge.

Fig. 2  Small signal modulation response of the air-bridge type mode-locked laser showing cavity resonance peak at around 21.8 GHz.

Fig. 3  Electrical spectrum of the mode-locked pulse train for (a) passive mode-locking, (b) hybrid mode-locking at 21.764 GHz, (c) hybrid mode-locking at 21.83 GHz.

Fig. 4  Schematic setup of a WDM dropping system showing a 85/15 coupler and a fiber bragg grating drop filter.

Fig. 5  Optical spectra of (a) all WDM channels, (b) dropped channel, (c) remaining channels. Note that all spectras have arbitrary referral levels.
Fig. 1

Absorber section

Gain section

Air-bridge

2010 µm

110 µm

SiO₂

n⁺ InP

Isolation channels

10 µm
Fig. 2
Fig. 3
Fig. 4

Multiwavelength mode-locked laser source

Dropped WDM channel (b) 15% 85/15 Coupler 15%

Remaining WDM channels 85% Bragg grating 85%

(a) All WDM channels
Fig. 5